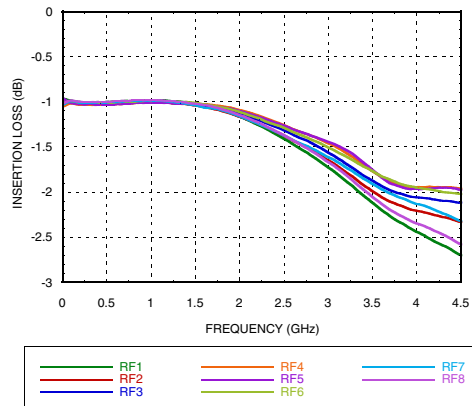
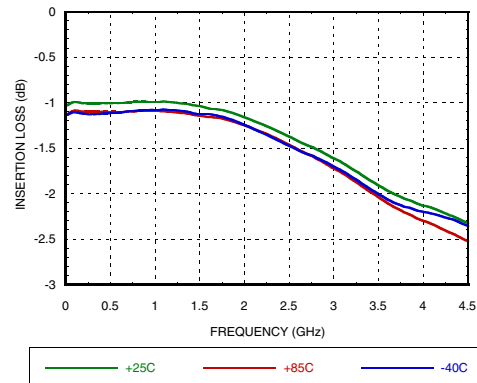


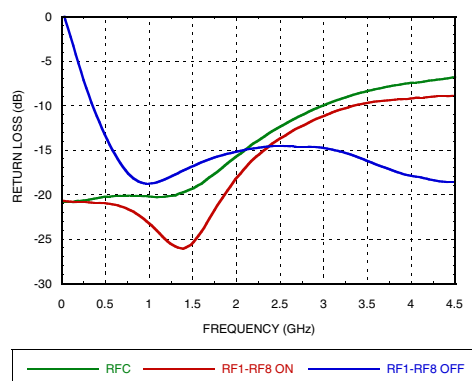
Insertion Loss



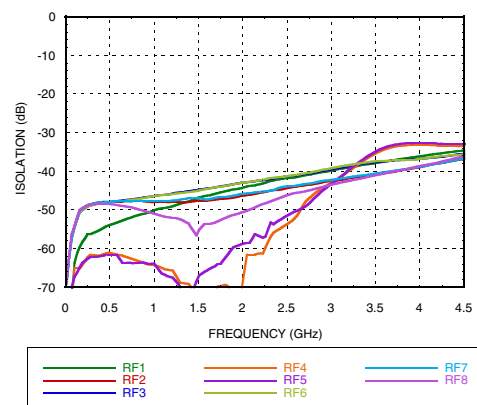
Insertion Loss vs. Temperature



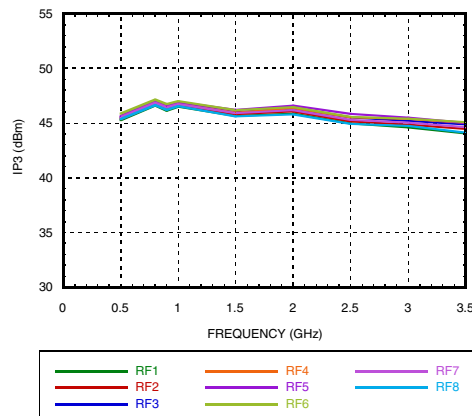
Return Loss



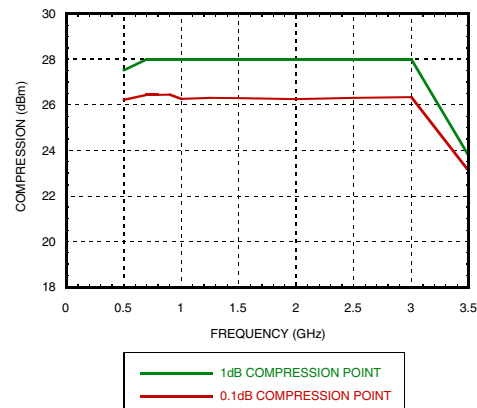
Isolation



Input IP3



Input Compression



GaAs MIMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

Bias Voltage & Current

Vdd Range = +5 Vdc \pm 10%		
Vdd (Vdc)	Idd (Typ.) (mA)	Idd (Max.) (mA)
+5	4.5	7.5

TTL/CMOS Control Voltages

State	Bias Condition
Low	0 to +0.8 Vdc @ <1 μ A Typ.
High	+2.0 to +5 Vdc @ 60 μ A Typ.

NOTE:

DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6, 7, 8.

Truth Table

Control Input			Signal Path State
A	B	C	RFCOM to:
Low	Low	Low	RF1
High	Low	Low	RF2
Low	High	Low	RF3
High	High	Low	RF4
Low	Low	High	RF5
High	Low	High	RF6
Low	High	High	RF7
High	High	High	RF8

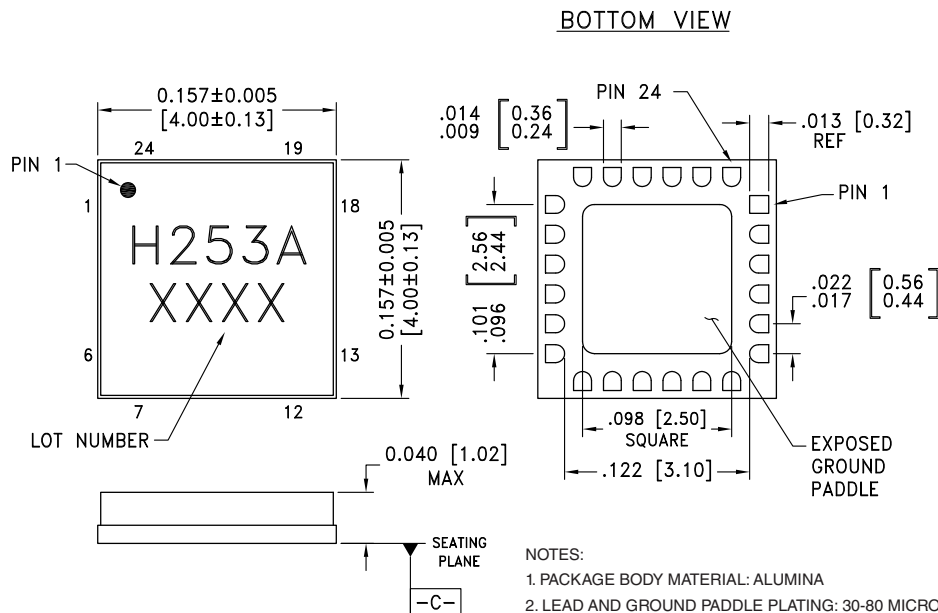


ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Absolute Maximum Ratings

Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A, B, C)	-0.5V to Vdd +1Vdc
Channel Temperature	150 °C
Thermal Resistance (channel to package ground paddle)	
Through Path	183 °C/W
Termination Path	274 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power (Vdd = +5V)	
Through Path	+20 dBm (0.05 - 0.5 GHz) +25 dBm (0.5 - 3.5 GHz)
Terminated Path	+20 dBm (0.05 - 0.5 GHz) +23.5 dBm (0.5 - 3.5 GHz)
ESD Sensitivity (HBM)	Class 1A


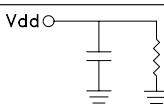
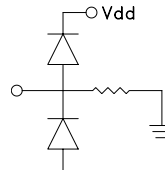
Outline Drawing

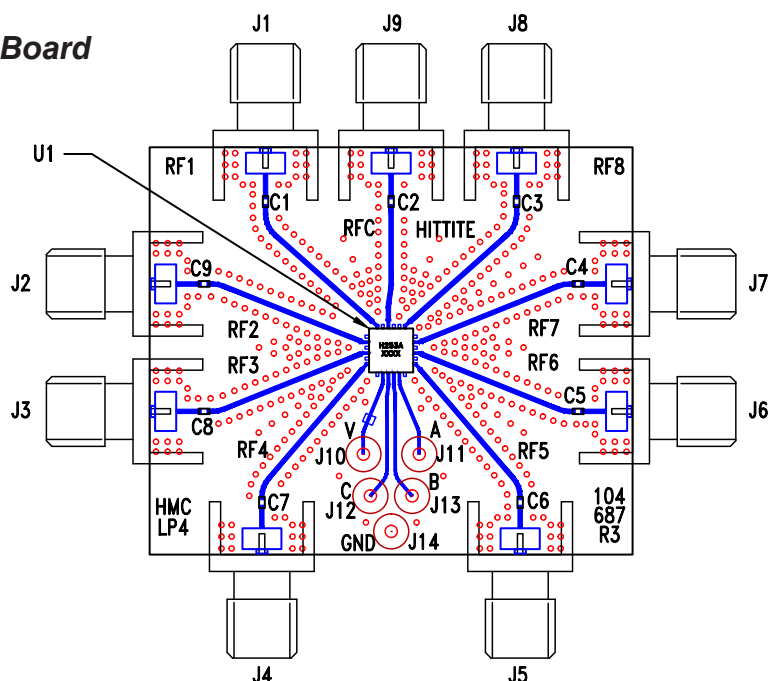


NOTES:

1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 5, 7, 12, 14, 16, 18, 20, 21, 23	GND	Package bottom has exposed metal paddle that must also be connected to RF ground.	
2, 4, 6, 13, 15, 17, 19, 22, 24	RF1 - RF8 & RFC	This pin is DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
8	Vdd	Supply Voltage +5 Vdc ±10%	
9	CTL C	See truth table and control voltage table.	
10	CTL B		
11	CTL A		

**GaAs MIMIC SP8T NON-REFLECTIVE
SWITCH, DC - 3.5 GHz**
Evaluation Circuit Board**List of Materials for Evaluation PCB EV1HMC253ALC4 [1]**

Item	Description
J1 - J9	PCB Mount SMA Connector
J10 - J14	DC Pin
C1 - C9	100 pF Capacitor, 0402 Pkg.
U1	HMC253ALC4 SP8T Switch
PCB [2]	104687 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.